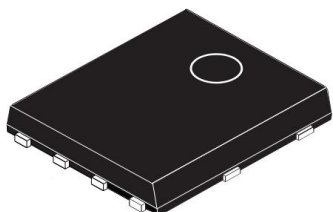


MBR15200DJF SCHOTTKY RECTIFIER

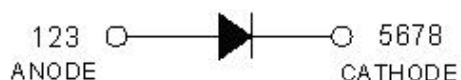


PDFNWB5×6-8L

Features

- Designed as Bypass Diodes for Solar Panels
- Selectively Rated for 200°C Maximum Junction Temperature
- for High Thermal Reliability
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- Terminals finish: 100% Pure Tin
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	200	V
Average Rectified Forward Current	$I_F (AV)$	50% duty cycle @ $T_C = 136^\circ\text{C}$, rectangular wave form	15	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3ms, Half Sine pulse, $T_C = 25^\circ\text{C}$	250	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 15 A, Pulse, $T_J = 25^\circ\text{C}$	0.85	0.92	V
	V_{F2}	@ 15 A, Pulse, $T_J = 125^\circ\text{C}$	0.72	0.76	V
Reverse Current*	I_{R1}	@ V_R = rated V_R $T_C = 25^\circ\text{C}$	0.0001	1.0	mA
Reverse Current*	I_{R2}	@ V_R = rated V_R $T_C = 125^\circ\text{C}$	0.1	10	mA
Junction Capacitance	C_T	@ $V_R = 5\text{V}$, $T_C = 25^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$	200	400	pF

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +200	°C
Storage Temperature	T_{stg}	-	-55 to +200	°C
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	DC operation	2.6	°C/W
Approximate Weight	wt	-	0.095	g

Ratings and Characteristics Curves

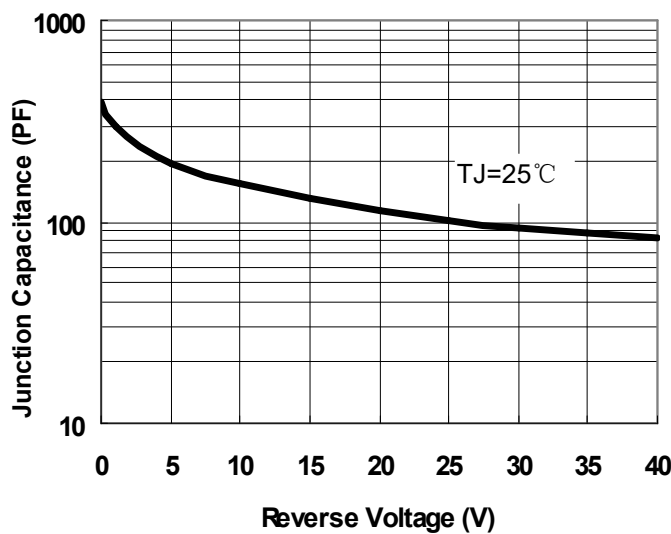


Fig.1-Typical Junction Capacitance

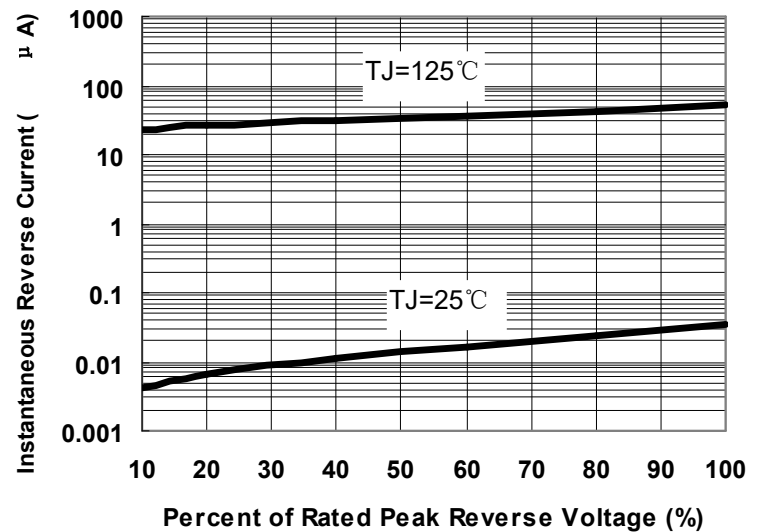


Fig.2-Typical Reverse Characteristics

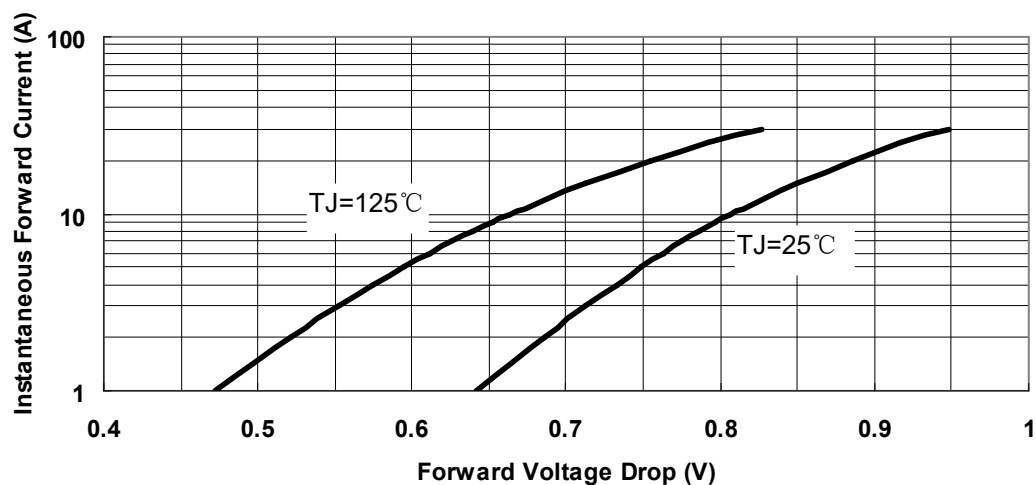
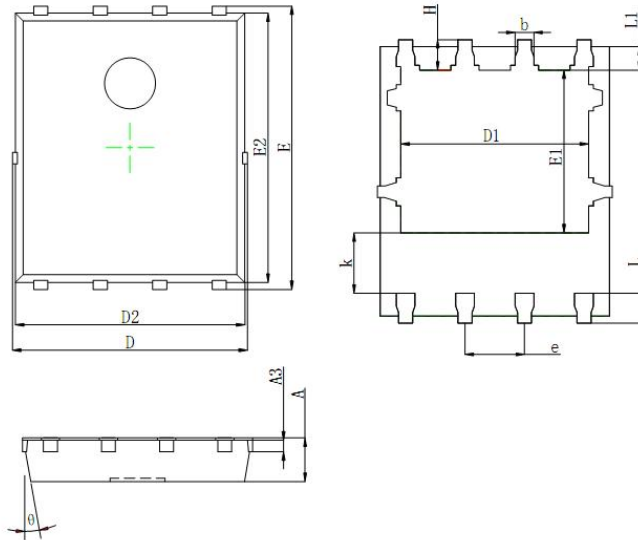
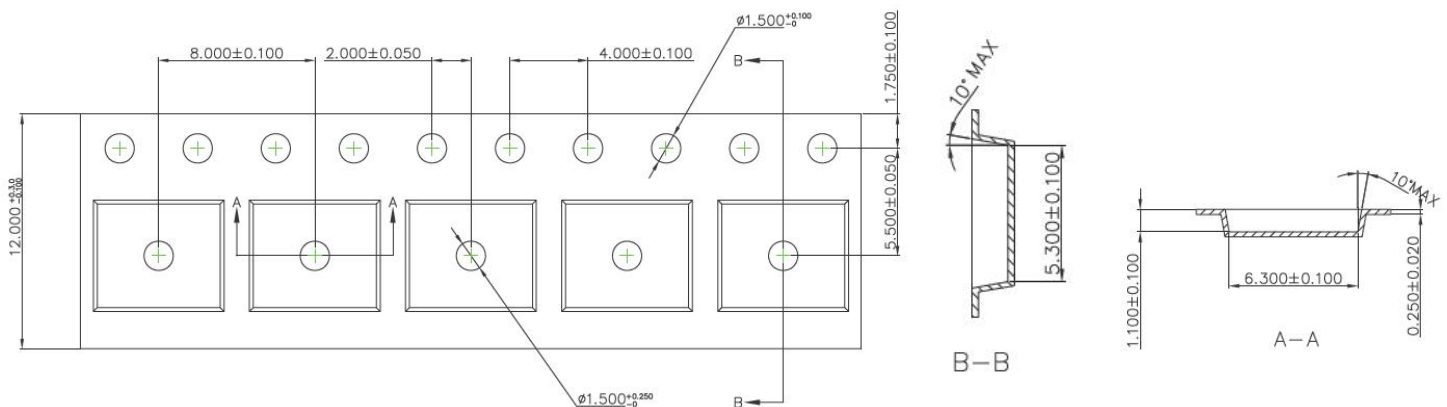


Fig.3-Typical Instantaneous Forward Voltage Characteristics

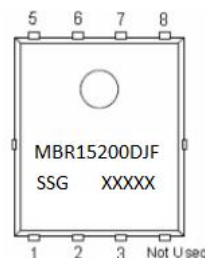
Mechanical Dimensions PDFNWB5×6-8L


SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254 REF.		0.010 REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
e	1.270 TYP.		0.050 TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
Θ	10°	12°	10°	12°

Carrier Tape Specification PDFNWB5×6-8L(mm)

Ordering Information

Device	Package	Shipping
MBR15200DJF	PDFNWB5×6-8L (Pb-Free)	3000 pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram


Where XXXXX is YYWWL

MBR = Device Type
 15 = Forward Current (15A)
 200 = Reverse Voltage (200V)
 DJF = Package type
 SSG = SSG
 YY = Year
 WW = Week
 L = Lot Number

Cautions: Molding resin
 Epoxy resin UL:94V-0

Technical Data
Data Sheet N1443, Rev. B



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